

Technical Data Data Sheet N0040, Rev. B

### **Green Products**

ANODE 1 ANODE 2

COMMON CATHODE BASE

# **MBR30100WT SCHOTTKY RECTIFIER**

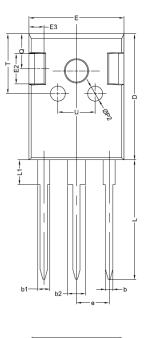
### **Applications:**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

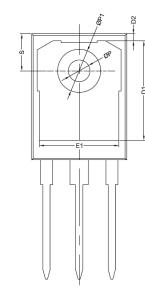
### Features:

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Mechanical Dimensions: In mm/Inches



<u>п</u>т



SYMBOL	MIN.	TYP.	MAX.
A	4.80	5.00	5.20
A1	2.21	2.41	2.61
A2	1.90	2.00	2.10
b	1.10	1.20	1.35
b1		2.00	
b2		3.00	
С	0.55	0.60	0.75
D	20.80	21.00	21.20
D1		16.55	
D2 E		1.20	
E	15.60	15.80	16.00
E1		13.30	
E2		5.00	
E3		2.50	
е		5.44	
L	19.42	19.92	20.42
L L1		4.13	
Р	3.50	3.60	3.70
P1			7.40
P2		2.50	
Q S T		5.80	
S	6.05	6.15	6.25
		10.00	
U		6.20	

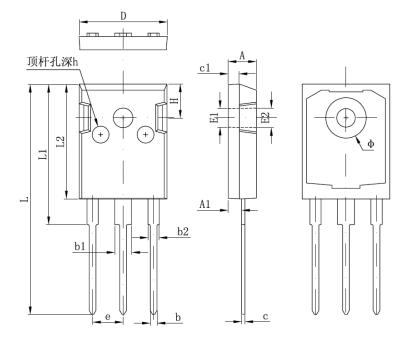
### **OPTION 1(HD)**

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Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
A	4.850	5.150	0.191	0.200		
A1	2.200	2.600	0.087	0.102		
b	1.000	1.400	0.039	0.055		
b1	2.800	3.200	0.110	0.126		
b2	1.800	2.200	0.071	0.087		
с	0.500	0.700	0.020	0.028		
c1	1.900	2.100	0.075	0.083		
D	15.450	15.750	0.608	0.620		
E1	3.500	3.500 REF		0.138 REF		
E2	3.600	3.600 REF		0.142 REF		
L	40.900	41.300	1.610	1.626		
L1	24.800	25.100	0.976	0.988		
L2	20.300	20.600	0.799	0.811		
Φ	7.100	7.300	0.280	0.287		
е	5.450 TYP		0.215 TYP			
Н	5.980 REF		0.235 REF			
h	0.000	0.300	0.000	0.012		

**OPTION 2(CJ)** 

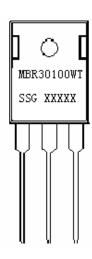
TO-247AD



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### Marking Diagram:



Where XXXXX is YYWWL

MBR	= Device Type
30	= Forward Current (30A)
100	= Reverse Voltage (100V)
WT	= Configuration
SSG	= SSG
ΥY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## **Ordering Information:**

Device	Package	Shipping	
MBR30100WT	TO-247AD (Pb-Free)	30pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	100	V
Average Rectified Forward Current(per device)	I <sub>F (AV)</sub>	50% duty cycle @T <sub>c</sub> =103°C, rectangular wave form	30	A
Peak Repetitive Forward Current(per leg)	I <sub>FRM</sub>	Rated V <sub>R</sub> square wave, 20KHz T <sub>C</sub> =133°C	20	A
Peak One Cycle Non-Repetitive Surge Current(per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	150	A

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 15A, Pulse, T <sub>J</sub> = 25 °C	0.78	0.85	V
(per leg)*		@ 30 A, Pulse, T <sub>J</sub> = 25 °C	0.90	1.05	v
	V <sub>F2</sub>	@ 15 A, Pulse, T <sub>J</sub> = 125 °C	0.65	0.70	V
		@ 30 A, Pulse, T <sub>J</sub> = 125 °C	0.77	0.85	v
Reverse Current (per leg) *	I <sub>R1</sub>	$@V_R = rated V_R$	0.003	1.0	mA
		T <sub>J</sub> = 25 °C	0.003	1.0	ША
	I <sub>R2</sub>	$@V_R = rated V_R$	2	15.0	mA
		T <sub>J</sub> = 125 °C	2	15.0	ША
Junction Capacitance	CT	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	380	500	pF
(per leg)		f <sub>SIG</sub> = 1MHz	300	300	рі
Series Inductance	Ls	Measured lead to lead 5 mm	8.0	_	nH
(per leg)		from package body	0.0	_	
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

\* Pulse Width < 300µs, Duty Cycle <2%

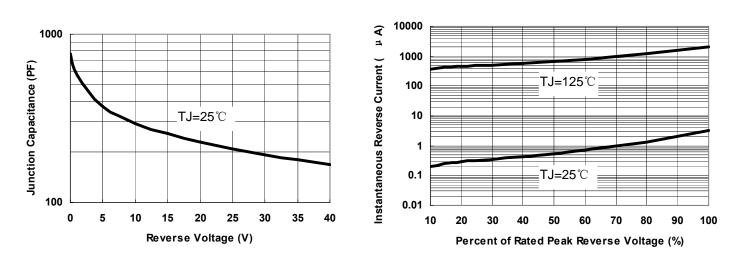
## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	2.0	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>θJA</sub>	DC operation	50	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>0CS</sub>	Mounting surface, smooth and greased	0.50	°C/W
Approximate Weight	wt	-	6.7	g
Case Style	TO-247AD			

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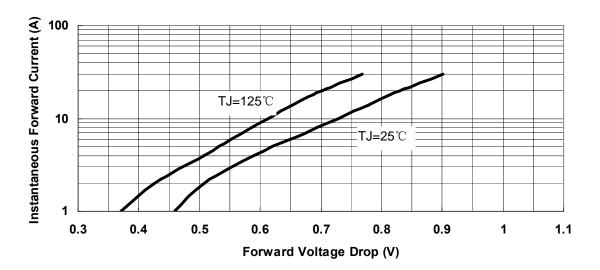


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### Fig.1-Typical Junction Capacitance

#### **Fig.2-Typical Reverse Characteristics**



#### Fig.3-Typical Instantaneous Forward Voltage Characteristics



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